

FEATURES

True rms-to-dc conversion

Laser trimmed to high accuracy

0.2% maximum error (AD536AK)

0.5% maximum error (AD536AJ)

Wide response capability

Computes rms of ac and dc signals

450 kHz bandwidth: $V_{rms} > 100 \text{ mV}$

2 MHz bandwidth: $V_{rms} > 1 \text{ V}$

Signal crest factor of 7 for 1% error

dB output with 60 dB range

Low power: 1.2 mA quiescent current

Single or dual supply operation

Monolithic integrated circuit

-55°C to $+125^\circ\text{C}$ operation (AD536AS)

GENERAL DESCRIPTION

The AD536A is a complete monolithic integrated circuit that performs true rms-to-dc conversion. It offers performance comparable or superior to that of hybrid or modular units costing much more. The AD536A directly computes the true rms value of any complex input waveform containing ac and dc components. A crest factor compensation scheme allows measurements with 1% error at crest factors up to 7. The wide bandwidth of the device extends the measurement capability to 300 kHz with less than 3 dB errors, for signal levels greater than 100 mV.

An important feature of the AD536A, not previously available in rms converters, is an auxiliary dB output pin. The logarithm of the rms output signal is brought out to a separate pin to allow the dB conversion, with a useful dynamic range of 60 dB. Using an externally supplied reference current, the 0 dB level can be conveniently set to correspond to any input level from 0.1 V to 2 V rms.

The AD536A is laser trimmed to minimize input and output offset voltage, to optimize positive and negative waveform symmetry (dc reversal error), and for full-scale accuracy at 7 V rms. As a result, no external trims are required to achieve the rated unit accuracy.

The input and output pins are fully protected. The input circuitry can take overload voltages well beyond the supply levels. Loss of supply voltage with the input connected to external circuitry does not cause the device to fail. The output is short-circuit protected.

Rev. C

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FUNCTIONAL BLOCK DIAGRAM

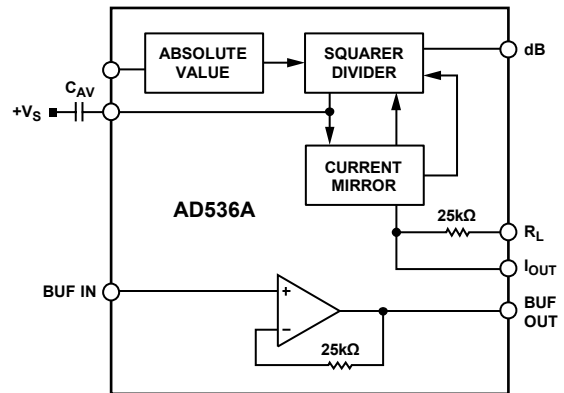


Figure 1.

00504-001

The AD536A is available in two accuracy grades (J and K) for commercial temperature range (0°C to 70°C) applications, and one grade (S) rated for the -55°C to $+125^\circ\text{C}$ extended range. The AD536AK offers a maximum total error of $\pm 2 \text{ mV} \pm 0.2\%$ of reading while the AD536AJ and AD536AS have maximum errors of $\pm 5 \text{ mV} \pm 0.5\%$ of reading. All three versions are available in a hermetically sealed 14-lead DIP or a 10-lead TO-100 metal can. The AD536AS is also available in a 20-terminal leadless hermetically sealed ceramic chip carrier.

The AD536A computes the true root-mean-square level of a complex ac (or ac plus dc) input signal and provides an equivalent dc output level. The true rms value of a waveform is a more useful quantity than the average rectified value because it relates directly to the power of the signal. The rms value of a statistical signal also relates to its standard deviation.

An external capacitor is required to perform measurements to the fully specified accuracy. The value of this capacitor determines the low frequency ac accuracy, ripple amplitude, and settling time.

The AD536A operates equally well from split supplies or a single supply with total supply levels from 5 V to 36 V. With one milliampere quiescent supply current, the device is well suited for a wide variety of remote controllers and battery-powered instruments.

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REVISION HISTORY**3/06—Rev. B to Rev. C**

Updated Format	Universal
Changed Product Description to General Description	1
Changes to General Description	1
Changes to Table 1	3
Changes to Table 2	5
Added Pin Configurations and Function Descriptions	6
Changed Standard Connection to Typical Connections	8
Changed Single Supply Connection to Single Supply Operation	9
Changes to Connections for dB Operation	11
Changes to Figure 17	12
Updated Outline Dimensions	14
Changes to Ordering Guide	15

6/99—Rev. A to Rev. B

SPECIFICATIONS

@ +25°C and ±15 V dc, unless otherwise noted.

Table 1.

Parameter	AD536AJ			AD536AK			AD536AS			Unit
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
TRANSFER FUNCTION	$V_{OUT} = \sqrt{\text{avg.}(V_{IN})^2}$			$V_{OUT} = \sqrt{\text{avg.}(V_{IN})^2}$			$V_{OUT} = \sqrt{\text{avg.}(V_{IN})^2}$			
CONVERSION ACCURACY										
Total Error, Internal Trim ¹ (Figure 6)	±5 ± 0.5			±2 ± 0.2			±5 ± 0.5			mV ± % of rdg
vs. Temperature, T _{MIN} to +70°C +70°C to +125°C	±0.1 ± 0.01			±0.05 ± 0.005			±0.1 ± 0.005 ±0.3 ± 0.005			mV ± % of rdg/°C mV ± % of rdg/°C
vs. Supply Voltage	±0.1 ±0.01			±0.1 ± 0.01			±0.1 ±0.01			mV ± % of rdg/°C mV ± % of rdg/°C
dc Reversal Error	±0.2			±0.1			±0.2			mV ± % of rdg
Total Error, External Trim ¹ (Figure 9)	±3 ± 0.3			±2 ± 0.1			±3 ± 0.3			mV ± % of rdg
ERROR VS. CREST FACTOR ²										
Crest Factor 1 to 2	Specified Accuracy			Specified Accuracy			Specified Accuracy			
Crest Factor = 3	-0.1			-0.1			-0.1			% of rdg
Crest Factor = 7	-1.0			-1.0			-1.0			% of rdg
FREQUENCY RESPONSE ³										
Bandwidth for 1% Additional Error (0.09 dB)										
V _{IN} = 10 mV	5			5			5			kHz
V _{IN} = 100 mV	45			45			45			kHz
V _{IN} = 1 V	120			120			120			kHz
±3 dB Bandwidth										
V _{IN} = 10 mV	90			90			90			kHz
V _{IN} = 100 mV	450			450			450			kHz
V _{IN} = 1 V	2.3			2.3			2.3			MHz
AVERAGING TIME CONSTANT (Figure 12)	25			25			25			ms/μF
INPUT CHARACTERISTICS										
Signal Range, ±15 V Supplies										
Continuous rms Level	0 to 7			0 to 7			0 to 7			V rms
Peak Transient Input	±20			±20			±20			V peak
Continuous rms Level, V _S = ±5 V	0 to 2			0 to 2			0 to 2			V rms
Peak Transient Input, V _S = ±5 V	±7			±7			±7			V peak
Maximum Continuous Nondestructive Input Level (All Supply Voltages)	±25			±25			±25			V peak
Input Resistance	13.33	16.67	20	13.33	16.67	20	13.33	16.67	20	kΩ
Input Offset Voltage	0.8 ± 2			0.5 ± 1			0.8 ± 2			mV
OUTPUT CHARACTERISTICS										
Offset Voltage, V _{IN} = COM (Figure 6)	±1 ± 2			±0.5 ± 1			±2			mV
vs. Temperature	±0.1			±0.1			±0.2			mV/°C
vs. Supply Voltage	±0.1			±0.1			±0.2			mV/V
Voltage Swing, ±15 V Supplies	0 to +11	+12.5		0 to +11	+12.5		0 to +11	+12.5		V
± 5 V Supply	0 to +2			0 to +2			0 to +2			V
dB OUTPUT, 0 dB = 1 V rms (Figure 17)										
Error, 7 mV < V _{IN} < 7 V rms	±0.4 ± 0.6			±0.2 ± 0.3			±0.5 ± 0.6			dB
Scale Factor	-3			-3			-3			mV/dB
Scale Factor Temperature Coefficient (Uncompensated)	-0.033			-0.033			-0.033			dB/°C
I _{REF} for 0 dB = 1 V rms	5	20	80	5	20	80	5	20	80	μA
I _{REF} Range	1 to 100			1 to 100			1 to 100			μA

AD536A

Parameter	AD536AJ			AD536AK			AD536AS			Unit
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{OUT} TERMINAL										
I _{OUT} Scale Factor		40			40			40		μA/V rms
I _{OUT} Scale Factor Tolerance		±10	±20		±10	±20		±10	±20	%
Output Resistance	20	25	30	20	25	30	20	25	30	kΩ
Voltage Compliance		-V _S to (+V _S - 2.5 V)			-V _S to (+V _S - 2.5 V)			-V _S to (+V _S - 2.5 V)		V
BUFFER AMPLIFIER										
Input and Output Voltage Range	-V _S to (+V _S - 2.5V)			-V _S to (+V _S - 2.5V)			-V _S to (+V _S - 2.5V)			V
Input Offset Voltage, R _S = 25 k		±0.5	±4		±0.5	±4		±0.5	±4	mV
Input Bias Current		20	60		20	60		20	60	nA
Input Resistance		10 ⁸			10 ⁸			10 ⁸		Ω
Output Current	(+5 mA, -130 μA)			(+5 mA, -130 μA)			(+5 mA, -130 μA)			
Short-Circuit Current		20			20			20		mA
Output Resistance			0.5			0.5			0.5	Ω
Small Signal Bandwidth		1			1			1		MHz
Slew Rate ⁴		5			5			5		V/μs
POWER SUPPLY										
Voltage Rated Performance		±15			±15			±15		V
Dual Supply	±3.0		±18	±3.0		±18	±3.0		±18	V
Single Supply	+5		+36	+5		+36	+5		+36	V
Quiescent Current										
Total V _S , 5 V to 36 V, T _{MIN} to T _{MAX}		1.2	2		1.2	2		1.2	2	mA
TEMPERATURE RANGE										
Rated Performance	0		+70	0		+70	-55		+125	°C
Storage	-55		+150	-55		+150	-55		+150	°C
NUMBER OF TRANSISTORS		65			65			65		

¹ Accuracy is specified for 0 V to 7 V rms, dc or 1 kHz sine wave input with the AD536A connected as in the figure referenced.

² Error vs. crest factor is specified as an additional error for 1 V rms rectangular pulse input, pulse width = 200 μs.

³ Input voltages are expressed in volts rms, and error is percent of reading.

⁴ With 2kΩ external pull-down resistor.

ABSOLUTE MAXIMUM RATINGS

Table 2.

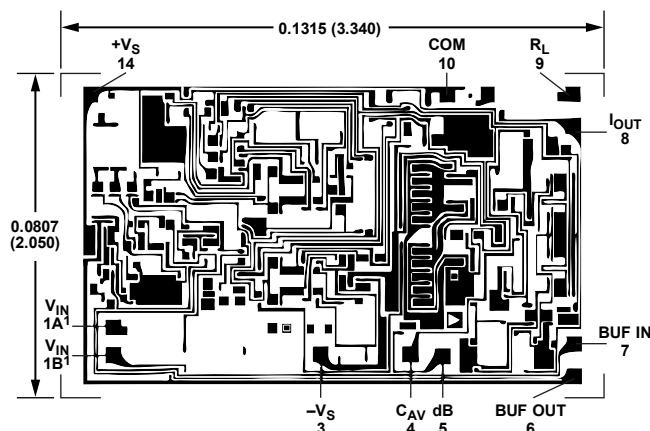
Parameter	Rating
Supply Voltage	
Dual Supply	± 18 V
Single Supply	+36 V
Internal Power Dissipation	500 mW
Maximum Input Voltage	± 25 V Peak
Buffer Maximum Input Voltage	$\pm V_S$
Maximum Input Voltage	± 25 V Peak
Storage Temperature Range	-55°C to $+150^\circ\text{C}$
Operating Temperature Range	
AD536AJ/AD536AK	0°C to $+70^\circ\text{C}$
AD536AS	-55°C to $+125^\circ\text{C}$
Lead Temperature (Soldering 60 seconds)	300°C
ESD Rating	1000 V
Thermal Resistance θ_{JA} ¹	
10-Lead Header	$150^\circ\text{C}/\text{W}$
20-Lead LCC	$95^\circ\text{C}/\text{W}$
14-Lead Side-Braced CERDIP	$95^\circ\text{C}/\text{W}$

¹ θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



PAD NUMBERS CORRESPOND TO PIN NUMBERS FOR THE TO-166 14-LEAD CERAMIC DIP PACKAGE.

¹BOTH PADS SHOWN MUST BE CONNECTED TO V_{IN} . THE AD536A IS AVAILABLE IN LASER TRIMMED CHIP FORM. SUBSTRATE CONNECTED TO $-V_S$.

00504-002

Figure 2. Die Dimensions and Pad Layout
Dimensions shown in inches and (millimeters)

AD536A

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

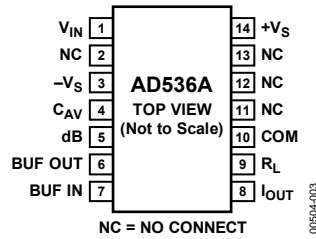


Figure 3. D-14 and Q-14 Packages Pin Configuration

Table 3. D-14 and Q-14 Packages Pin Function Descriptions

Pin No.	Mnemonic	Description
1	V_{IN}	Input Voltage
2	NC	No Connection
3	$-V_S$	Negative Supply Voltage
4	C_{AV}	Averaging Capacitor
5	dB	Log (dB) Value of the RMS Output Voltage
6	BUF OUT	Buffer Output
7	BUF IN	Buffer Input
8	I_{OUT}	RMS Output Current
9	R_L	Load Resistor
10	COM	Common
11	NC	No Connection
12	NC	No Connection
13	NC	No Connection
14	$+V_S$	Positive Supply Voltage

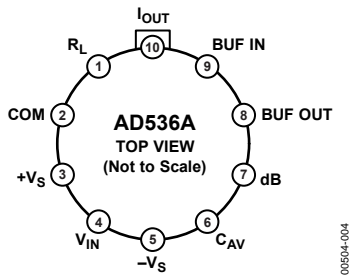


Figure 4. H-10 Package Pin Configuration

Table 4. H-10 Package Pin Function Descriptions

Pin No.	Mnemonic	Description
1	R_L	Load Resistor
2	COM	Common
3	$+V_S$	Positive Supply Voltage
4	V_{IN}	Input Voltage
5	$-V_S$	Negative Supply Voltage
6	C_{AV}	Averaging Capacitor
7	dB	Log (dB) Value of the RMS Output Voltage
8	BUF OUT	Buffer Output
9	BUF IN	Buffer Input
10	I_{OUT}	RMS Output Current

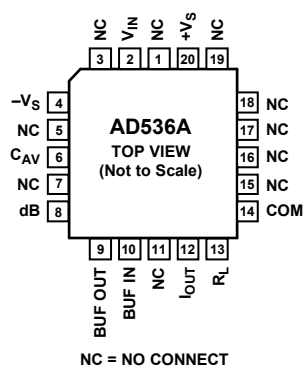


Figure 5. E-20 Package Pin Configuration

Table 5. E-20 Package Pin Function Description

Pin No.	Mnemonic	Description
1	NC	No Connection
2	V_{IN}	Input Voltage
3	NC	No Connection
4	$-V_S$	Negative Supply Voltage
5	NC	No Connection
6	C_{AV}	Averaging Capacitor
7	NC	No Connection
8	dB	Log (dB) Value of the RMS Output Voltage
9	BUF OUT	Buffer Output
10	BUF IN	Buffer Input
11	NC	No Connection
12	I_{OUT}	RMS Output Current
13	R_L	Load Resistor
14	COM	Common
15	NC	No Connection
16	NC	No Connection
17	NC	No Connection
18	NC	No Connection
19	NC	No Connection
20	$+V_S$	Positive Supply Voltage

APPLICATIONS

TYPICAL CONNECTIONS

The AD536A is simple to connect for the majority of high accuracy rms measurements, requiring only an external capacitor to set the averaging time constant. The standard connection is shown in Figure 6 through Figure 8. In this configuration, the AD536A measures the rms of the ac and dc level present at the input, but shows an error for low frequency input as a function of the filter capacitor, C_{AV} , as shown in Figure 12. Thus, if a 4 μF capacitor is used, the additional average error at 10 Hz is 0.1%; at 3 Hz, the additional average error is 1%.

The accuracy at higher frequencies is according to specification. To reject the dc input, add a capacitor in series with the input, as shown in Figure 10. Note that the capacitor must be nonpolar. If the AD536A supply rails contain a considerable amount of high frequency ripple, it is advisable to bypass both supply pins to ground with 0.1 μF ceramic capacitors, located as close to the device as possible.

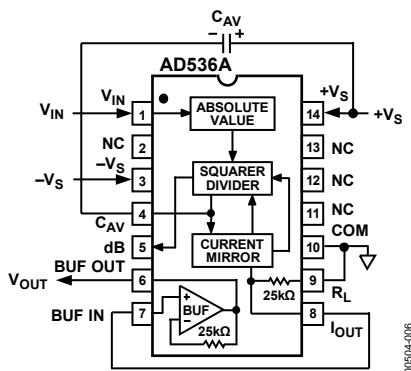


Figure 6. TO-116 and Q-14 Standard RMS Connection

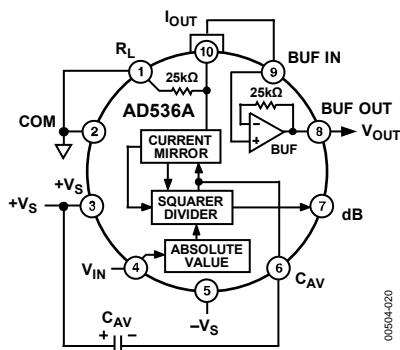


Figure 7. TO-100 Standard RMS Connection

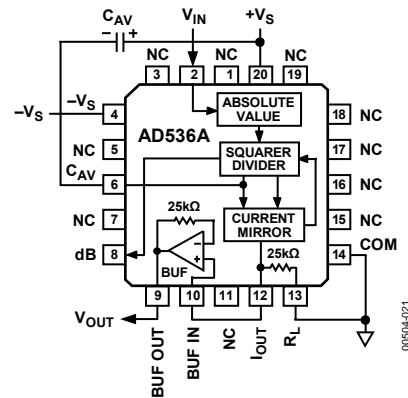


Figure 8. LCC Standard RMS Connection

The input and output signal ranges are a function of the supply voltages; these ranges are shown in Figure 21 and Figure 22.

The AD536A can also be used in an unbuffered voltage output mode by disconnecting the input to the buffer. The output then appears unbuffered across the 25 k Ω resistor. The buffer amplifier can then be used for other purposes. Further, the AD536A can be used in a current output mode by disconnecting the 25 k Ω resistor from ground. The output current is available at Pin 8 (Pin 10 on the H-10 package) with a nominal scale of 40 μA per V rms input positive out.

OPTIONAL EXTERNAL TRIMS FOR HIGH ACCURACY

The accuracy and offset voltage of the AD536A is adjustable with external trims, as shown in Figure 9. R4 trims the offset. Note that the offset trim circuit adds 365 Ω in series with the internal 25 k Ω resistor. This causes a 1.5% increase in scale factor, which is compensated by R1. The scale factor adjustment range is $\pm 1.5\%$.

The trimming procedure is as follows:

1. Ground the input signal, V_{IN} , and adjust R4 to provide 0 V output from Pin 6. Alternatively, adjust R4 to provide the correct output with the lowest expected value of V_{IN} .
2. Connect the desired full-scale input level to V_{IN} , either dc or a calibrated ac signal (1 kHz is the optimum frequency).
3. Trim R1 to provide the correct output at Pin 6. For example, 1.000 V dc input provides 1.000 V dc output. A ± 1.000 V peak-to-peak sine wave should provide a 0.707 V dc output. Any residual errors are caused by device nonlinearity.

The major advantage of external trimming is to optimize device performance for a reduced signal range; the AD536A is internally trimmed for a 7 V rms full-scale range.

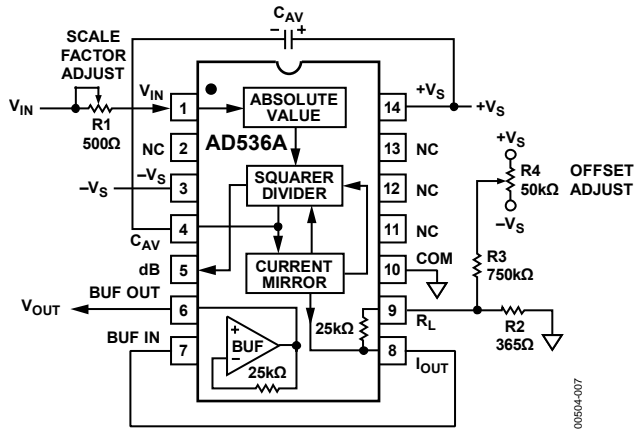


Figure 9. Optional External Gain and Output Offset Trims

SINGLE SUPPLY OPERATION

Dual power supplies are shown in Figure 6, Figure 7, Figure 8, and Figure 9. The AD536A may also be powered by a single supply greater than 5 V, as shown in Figure 10. When using the AD536A with a single supply, the differential input stage must be biased above ground, and the input must be ac coupled. Biasing the device between the supply and ground is simply a matter of connecting Pin 10 (COM, Pin 2 on the H10 package) to a resistor divider and bypassing the pin to ground. To minimize power consumption, the values of the resistors may be large as Pin 10 current is only 5 μ A.

AC input coupling requires only Capacitor C2. A dc return is not necessary because it is provided internally. C2 is selected for the proper low frequency break point with the input resistance of 16.7 k Ω ; for a cutoff at 10 Hz, C2 should be 1 μ F. The signal ranges in this connection are slightly more restricted than in the dual supply connection. The input and output signal ranges are shown in Figure 21 and Figure 22. The load resistor, R_L, is necessary to provide output sink current.

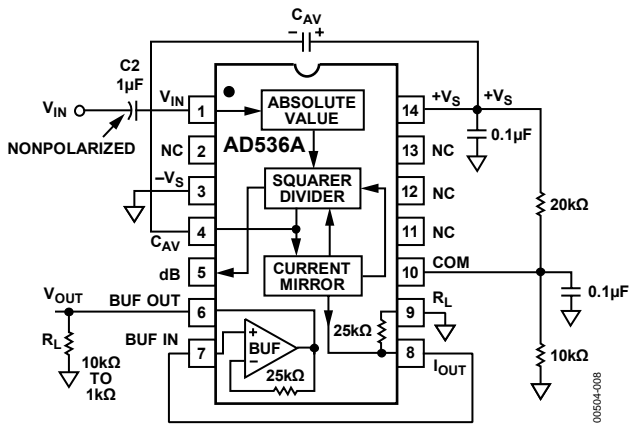


Figure 10. Single Supply Connection

CHOOSING THE AVERAGING TIME CONSTANT

The AD536A computes the rms of both ac and dc signals. If the input is a slowly varying dc signal, the output of the AD536A tracks the input exactly.

At higher frequencies, the average output of the AD536A approaches the rms value of the input signal. The actual output of the AD536A differs from the ideal output by a dc (or average) error and some amount of ripple, as shown in Figure 11.

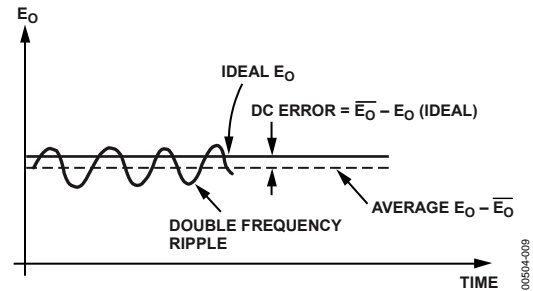


Figure 11. Typical Output Waveform for Sinusoidal Input

The dc error is dependent on the input signal frequency and the value of C_{AV}. Use Figure 12 to determine the minimum value of C_{AV}, which yields a given percent dc error above a given frequency using the standard rms connection.

The ac component of the output signal is the ripple. There are two ways to reduce the ripple. The first method involves using a large value of C_{AV}. Because the ripple is inversely proportional to C_{AV}, a tenfold increase in this capacitance affects a tenfold reduction in ripple.

When measuring waveforms with high crest factors, such as low duty cycle pulse trains, the averaging time constant should be at least 10 times the signal period. For example, a 100 Hz pulse rate requires a 100 ms time constant, which corresponds to a 4 μ F capacitor (time constant = 25 ms per μ F).

AD536A

The primary disadvantage in using a large C_{AV} to remove ripple is that the settling time for a step change in input level is increased proportionately. Figure 12 illustrates that the relationship between C_{AV} and 1% settling time is 115 ms for each microfarad of C_{AV} . The settling time is twice as great for decreasing signals as for increasing signals. The values in Figure 12 are for decreasing signals. Settling time also increases for low signal levels, as shown in Figure 13.

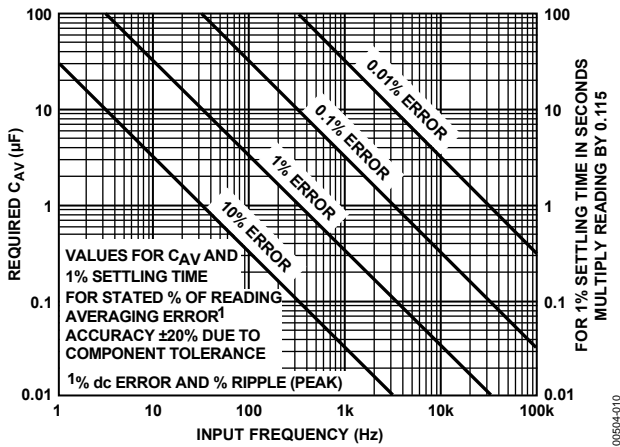


Figure 12. Error/Settling Time Graph for Use with the Standard RMS Connection (See Figure 6 Through Figure 8)

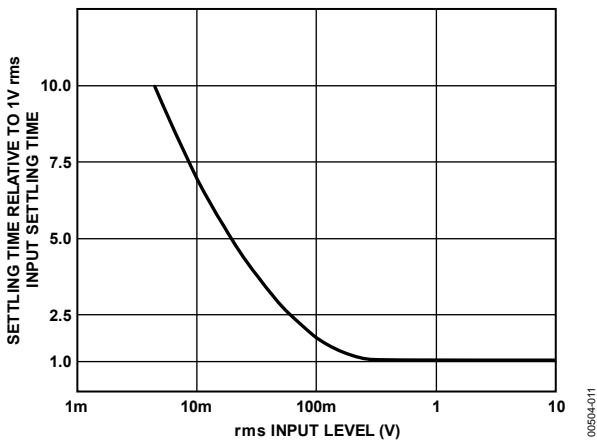


Figure 13. Settling Time vs. Input Level

A better method to reduce output ripple is the use of a post filter. Figure 14 shows a suggested circuit. If a single-pole filter is used (C_3 removed, R_x shorted), and C_2 is approximately twice the value of C_{AV} , the ripple is reduced, as shown in Figure 15, and settling time is increased. For example, with $C_{AV} = 1 \mu\text{F}$ and $C_2 = 2.2 \mu\text{F}$, the ripple for a 60 Hz input is reduced from 10% of reading to approximately 0.3% of reading.

The settling time, however, is increased by approximately a factor of 3. Therefore, the values of C_{AV} and C_2 can be reduced to permit faster settling times while still providing substantial ripple reduction.

The two-pole post filter uses an active filter stage to provide even greater ripple reduction without substantially increasing the settling times over a circuit with a one-pole filter. The values of C_{AV} , C_2 , and C_3 can then be reduced to allow extremely fast settling times for a constant amount of ripple. Caution should be exercised in choosing the value of C_{AV} , because the dc error is dependent upon this value and is independent of the post filter.

For a more detailed explanation of these topics, refer to the [RMS-to-DC Conversion Application Guide 2nd Edition](#), available from Analog Devices, Inc.

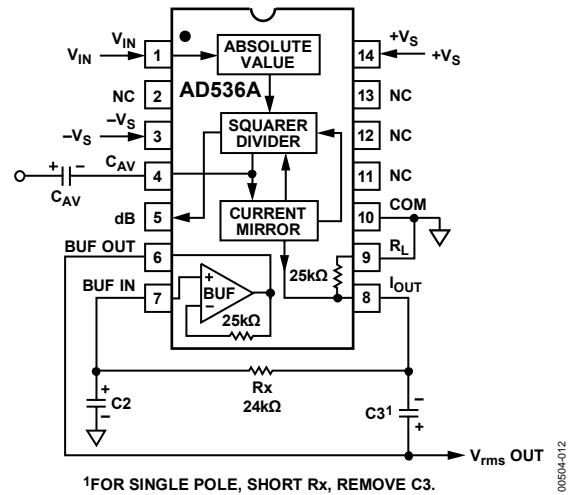


Figure 14. Two-Pole Post Filter

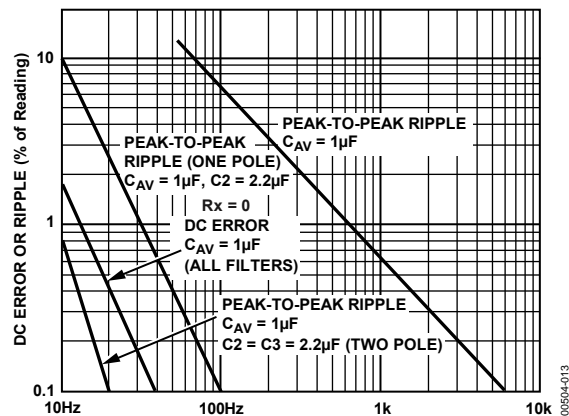


Figure 15. Performance Features of Various Filter Types (See Figure 7)

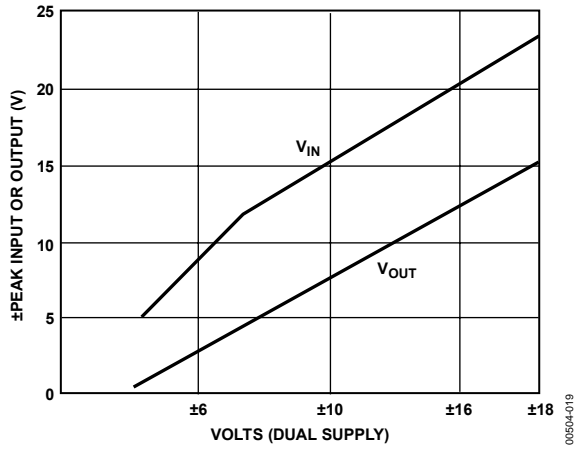


Figure 21. Input and Output Voltage Ranges vs. Dual Supply

00504-019

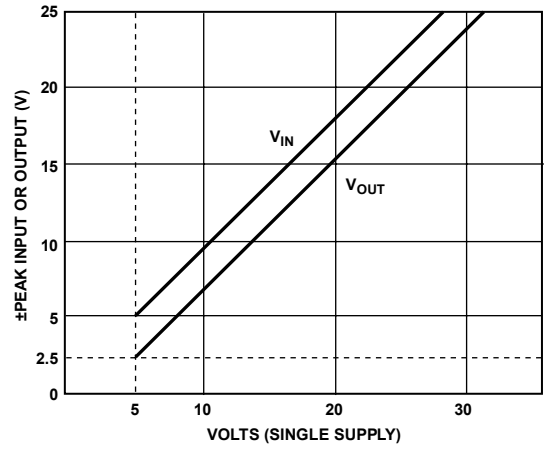
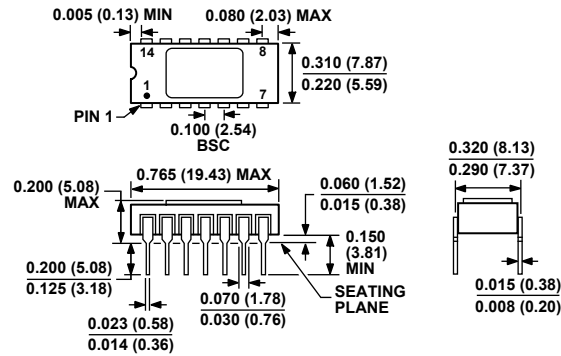


Figure 22. Input and Output Voltage Ranges vs. Single Supply

00504-022

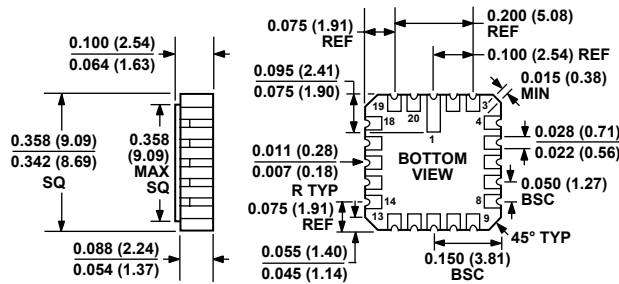
OUTLINE DIMENSIONS



CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 23. 14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP] (D-14)

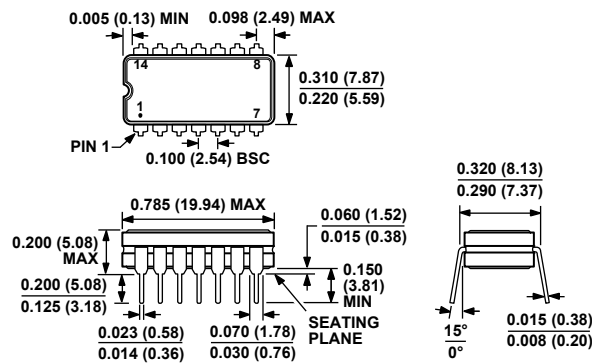
Dimensions shown in inches and (millimeters)



CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 24. 20-Terminal Ceramic Leadless Chip Carrier [LCC] (E-20)

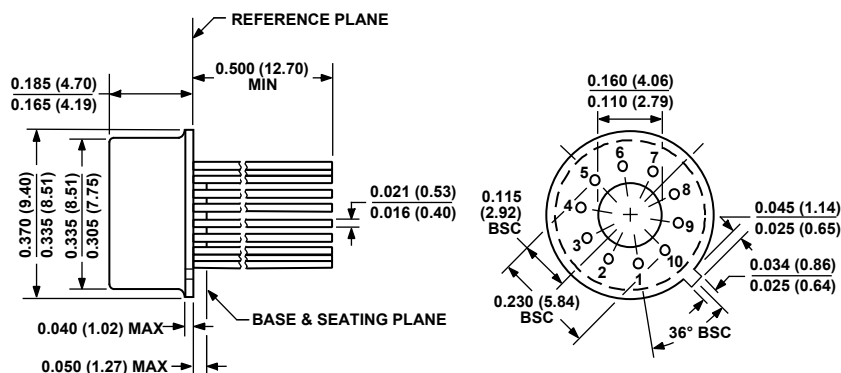
Dimensions shown in inches and (millimeter)



CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 25. 14-Lead Ceramic Dual In-Line Package [CERDIP] (Q-14)

Dimensions shown in inches and (millimeters)



DIMENSIONS PER JEDEC STANDARDS MO-006-AF
 CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS
 (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR
 REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 26. 10-Pin Metal Header Package [TO-100]
 (H-10)

Dimensions shown in inches and (millimeters)

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD536AJD	0°C to +70°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD536AKD	0°C to +70°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD536AJH	0°C to +70°C	10-Lead Metal Header Package [TO-100]	H-10
AD536AKH	0°C to +70°C	10-Lead Metal Header Package [TO-100]	H-10
AD536AJQ	0°C to +70°C	14-Lead Ceramic Dual In-Line Package [CERDIP]	Q-14
AD536AKQ	0°C to +70°C	14-Lead Ceramic Dual In-Line Package [CERDIP]	Q-14
AD536ASD	-55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD536ASD/883B	-55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD536ASE/883B	-55°C to +125°C	20-Terminal Ceramic Leadless Chip Carrier [LCC]	E-20
AD536ASH	-55°C to +125°C	10-Lead Metal Header Package [TO-100]	H-10
AD536ASH/883B	-55°C to +125°C	10-Lead Metal Header Package [TO-100]	H-10
AD536ASCHIPS	-55°C to +125°C	Die	
5962-89805012A	-55°C to +125°C	20-Terminal Ceramic Leadless Chip Carrier [LCC]	E-20
5962-8980501CA	-55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
5962-8980501IA	-55°C to +125°C	10-Lead Metal Header Package [TO-100]	H-10

AD536A

NOTES